

Document No.	853-0604
ECN No.	99800
Date of Issue	June 14, 1990
Status	Product Specification
ECL Products	

100101

Triple 5-Input OR/NOR Gate

FEATURES

- Typical propagation delay: 0.75ns
- Typical supply current ($-I_{EE}$): 27mA

DESCRIPTION

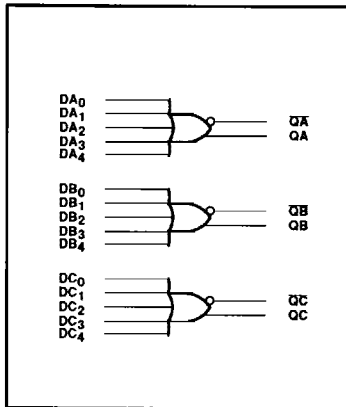
The 100101 is a triple 5-input OR/NOR gate.

All unused inputs can be left open due to integrated pull-down resistors.

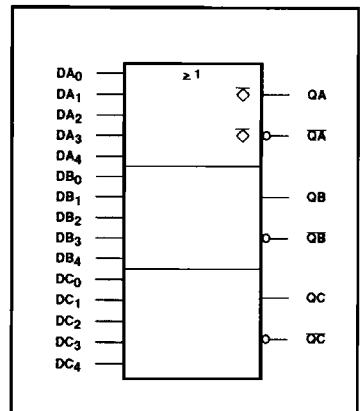
PIN DESCRIPTION

PINS	DESCRIPTION
DA ₀ - DA ₄ , DB ₀ - DB ₄ , DC ₀ - DC ₄	Data Inputs
QA, QB, QC	True Data Outputs (OR)
\overline{QA} , \overline{QB} , \overline{QC}	Complementary Data Outputs (NOR)

LOGIC DIAGRAM



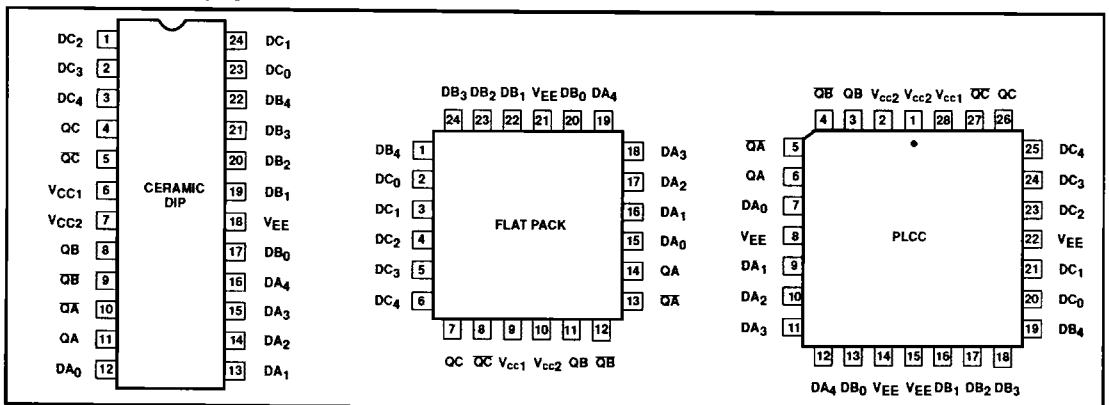
IEC/IEEE SYMBOL



ORDERING INFORMATION

DESCRIPTION	ORDER CODE
24-Pin Ceramic DIP (400 mils wide)	100101F
24-Pin Ceramic Flat Pack	100101Y
28-Pin PLCC	100101A

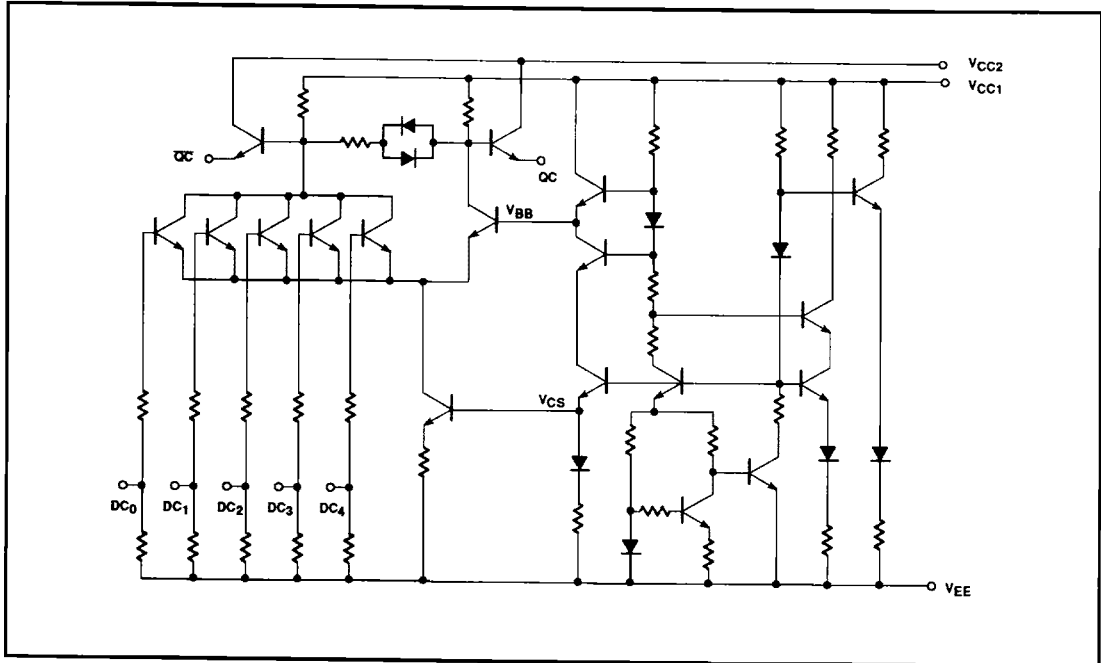
PIN CONFIGURATIONS



Gate

100101

SIMPLIFIED SCHEMATIC



FUNCTION TABLE

INPUTS					OUTPUTS	
DA ₀	DA ₁	DA ₂	DA ₃	DA ₄	QĀ	QA
L	L	L	L	L	H	L
H	X	X	X	X	L	H
X	H	X	X	X	L	H
X	X	H	X	X	L	H
X	X	X	H	X	L	H
X	X	X	X	H	L	H

NOTES:

- H = High voltage level
- L = Low voltage level
- X = Don't care

ABSOLUTE MAXIMUM RATINGS V_{CC1} = V_{CC2} = ground, T_A = 0°C to +85°C unless otherwise specified.

SYMBOL	PARAMETER	LIMITS	UNIT
V _{EE}	Supply voltage range	-7.0 to +0.5	V
V _{IN}	Input voltage (V _{IN} should never be more negative than V _{EE})	V _{EE} to +0.5	V
I _O	Output source current (continuous)	-55	mA
T _S	Storage temperature range	-65 to +150	°C
T _J	Maximum junction temperature	+150	°C

NOTE:

Operation beyond the limits set forth in this table may impair the useful life of the device.

Gate

100101

DC OPERATING CONDITIONS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN.	NOM.	MAX.	
V_{CC1}, V_{CC2}	Circuit ground		0	0	0	V
V_{EE}	Supply voltage		-4.8	-4.5	-4.2	V
V_{EE}	Supply voltage when operating with the 10K or the 10KH ECL family.		-5.7			V
V_{IH}	High level input voltage	$V_{EE} = -4.2V$	-1150		-880	mV
		$V_{EE} = -4.5V$	-1165			
		$V_{EE} = -4.8V$	-1165			
V_{IL}	Low level input voltage	$V_{EE} = -4.2V$	-1810		-1475	mV
		$V_{EE} = -4.5V$			-1475	mV
		$V_{EE} = -4.8V$			-1490	mV
T_A	Operating ambient temperature range		0	+25	+85	°C

NOTE:

When operating at other than the specified V_{EE} voltages (-4.2V, -4.5V, -4.8V), the DC and AC electrical characteristics will vary slightly from their specified values.

DC ELECTRICAL CHARACTERISTICS $V_{CC1} = V_{CC2} = \text{ground}, V_{EE} = -4.8V \text{ to } -4.2V, T_A = 0^\circ\text{C to } +85^\circ\text{C}$ unless otherwise specified^{1,3,4}

SYMBOL	PARAMETER	TEST CONDITIONS ²	LIMITS			UNIT	
			MIN.	TYP.	MAX.		
V_{OH}	High level output voltage	Inputs at V_{IHMAX} or V_{ILMIN} .	$V_{EE} = -4.2V$	-1020		-870	mV
			$V_{EE} = -4.5V$	-1025	-955	-880	mV
			$V_{EE} = -4.8V$	-1035		-880	mV
V_{OHT}	High level output threshold voltage	Outputs Loaded	Apply V_{IHMIN} or V_{ILMAX} to one input at a time, other inputs at V_{IHMAX} or V_{ILMIN} .	$V_{EE} = -4.2V$	-1030		mV
			$V_{EE} = -4.5V$	-1035		mV	
			$V_{EE} = -4.8V$	-1045		mV	
V_{OLT}	Low level output threshold voltage	with 50Ω to -2.0V ± 0.010V	Apply V_{IHMIN} or V_{ILMAX} to one input at a time, other inputs at V_{IHMAX} or V_{ILMIN} .	$V_{EE} = -4.2V$		-1595	mV
			$V_{EE} = -4.5V$		-1610	mV	
			$V_{EE} = -4.8V$		-1610	mV	
V_{OL}	Low level output voltage	Inputs at V_{IHMAX} or V_{ILMIN} .	$V_{EE} = -4.2V$	-1810		-1605	mV
			$V_{EE} = -4.5V$	-1810	-1705	-1620	mV
			$V_{EE} = -4.8V$	-1830		-1620	mV
I_{IH}	High level input current	One input under test at V_{IHMAX} . Other inputs at V_{ILMIN} .				350	μA
I_{IL}	Low level input current	One input under test at V_{ILMIN} . Other inputs at V_{IHMAX} .	0.5				μA
$-I_{EE}$	V_{EE} supply current	All inputs at V_{IHMAX} .	18	27	38		mA

NOTES:

- The specified limits represent the worst case values for the parameter. Since these worst case values normally occur at the supply voltage and temperature extremes, additional noise immunity can be achieved by decreasing the allowable operating condition ranges.
- Conditions for testing shown in the tables are not necessarily worst case. For worst case testing guidelines, refer to DC Testing, Chapter 1, Section 3.
- The specified limits shown in the DC electrical characteristics table can be met only after thermal equilibrium has been established. Thermal equilibrium is established by applying power for at least 2 minutes, while maintaining transverse airflow of 2.5 meters/sec (500 linear feet/min) over the device, mounted either in a test socket or on a printed circuit board. Test voltage values are given in the DC operating conditions table.
- The device can function down to $V_{EE} = -5.7V$, allowing operation with either the 10K or the 10KH family. Correction factors can be used to calculate new DC limits for the extended V_{EE} range. For more information, see Chapters 5 and 10, Section 4.

Gate

100101

AC ELECTRICAL CHARACTERISTICS

Ceramic DIP $V_{CC1} = V_{CC2} = \text{ground}$, $V_{EE} = -4.8\text{V to } -4.2\text{V}$

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			$T_A = 0^\circ\text{C}$		$T_A = +25^\circ\text{C}$		$T_A = +85^\circ\text{C}$		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay DA_n to QA and \overline{QA} , DB_n to QB and \overline{QB} , DC_n to QC and \overline{QC}	Waveform 1	0.50	1.15	0.50	1.15	0.55	1.30	ns
			0.50	1.15	0.50	1.15	0.55	1.30	ns
t_{TLH} t_{THL}	Transition time for all outputs		0.45	1.20	0.45	1.10	0.45	1.10	ns
			0.45	1.20	0.45	1.10	0.45	1.10	ns

NOTE:

For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC ELECTRICAL CHARACTERISTICS

Ceramic DIP $V_{CC1} = V_{CC2} = \text{ground}$, $V_{EE} = -5.2\text{V} \pm 5\%$

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			$T_A = 0^\circ\text{C}$		$T_A = +25^\circ\text{C}$		$T_A = +85^\circ\text{C}$		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay DA_n to QA and \overline{QA} , DB_n to QB and \overline{QB} , DC_n to QC and \overline{QC}	Waveform 1	0.50	1.15	0.50	1.15	0.55	1.30	ns
			0.50	1.15	0.50	1.15	0.55	1.30	ns
t_{TLH} t_{THL}	Transition time for all outputs		0.45	1.20	0.45	1.10	0.45	1.10	ns
			0.45	1.20	0.45	1.10	0.45	1.10	ns

NOTE:

For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC ELECTRICAL CHARACTERISTICS

Flat Pack and PLCC $V_{CC1} = V_{CC2} = \text{ground}$, $V_{EE} = -4.8\text{V to } -4.2\text{V}$

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			$T_A = 0^\circ\text{C}$		$T_A = +25^\circ\text{C}$		$T_A = +85^\circ\text{C}$		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay DA_n to QA and \overline{QA} , DB_n to QB and \overline{QB} , DC_n to QC and \overline{QC}	Waveform 1	0.50	0.95	0.50	0.95	0.55	1.10	ns
			0.50	0.95	0.50	0.95	0.55	1.10	ns
t_{TLH} t_{THL}	Transition time for all outputs		0.45	1.20	0.45	1.10	0.45	1.10	ns
			0.45	1.20	0.45	1.10	0.45	1.10	ns

NOTE:

For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC ELECTRICAL CHARACTERISTICS

Flat Pack and PLCC $V_{CC1} = V_{CC2} = \text{ground}$, $V_{EE} = -5.2\text{V} \pm 5\%$

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			$T_A = 0^\circ\text{C}$		$T_A = +25^\circ\text{C}$		$T_A = +85^\circ\text{C}$		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay DA_n to QA and \overline{QA} , DB_n to QB and \overline{QB} , DC_n to QC and \overline{QC}	Waveform 1	0.50	0.95	0.50	0.95	0.55	1.10	ns
			0.50	0.95	0.50	0.95	0.55	1.10	ns
t_{TLH} t_{THL}	Transition time for all outputs		0.45	1.20	0.45	1.10	0.45	1.10	ns
			0.45	1.20	0.45	1.10	0.45	1.10	ns

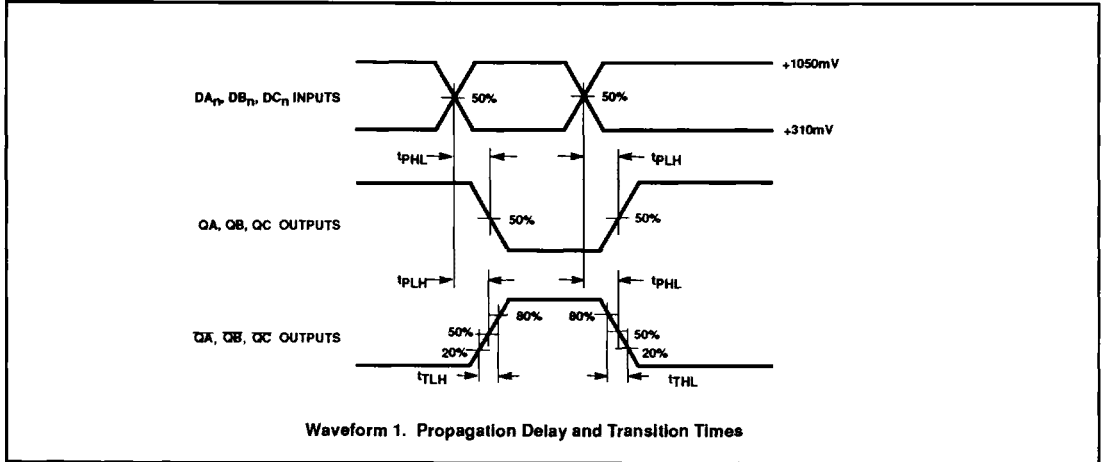
NOTE:

For AC test setup information, see AC Testing, Chapter 2, Section 3.

Gate

100101

AC WAVEFORMS



NOTE:
All power and signal voltages shifted up 2.0V for AC bench test purposes.